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FDG6306P

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P-Channel 2.5V Specified PowerTrench^o MOSFET

General Description

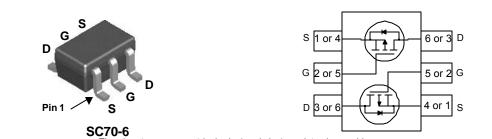
This PChannel 2.5V specified MOSFET is a rugged gate version of ON Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V – 12V).

Applications

- Battery management
- · Load switch

Features

- -0.6 A, -20 V. $R_{DS(ON)} = 420 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$ $R_{DS(ON)} = 630 \text{ m}\Omega @ V_{GS} = -2.5 \text{ V}$
- Low gate charge
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- Compact industry standard SC70-6 surface mount package



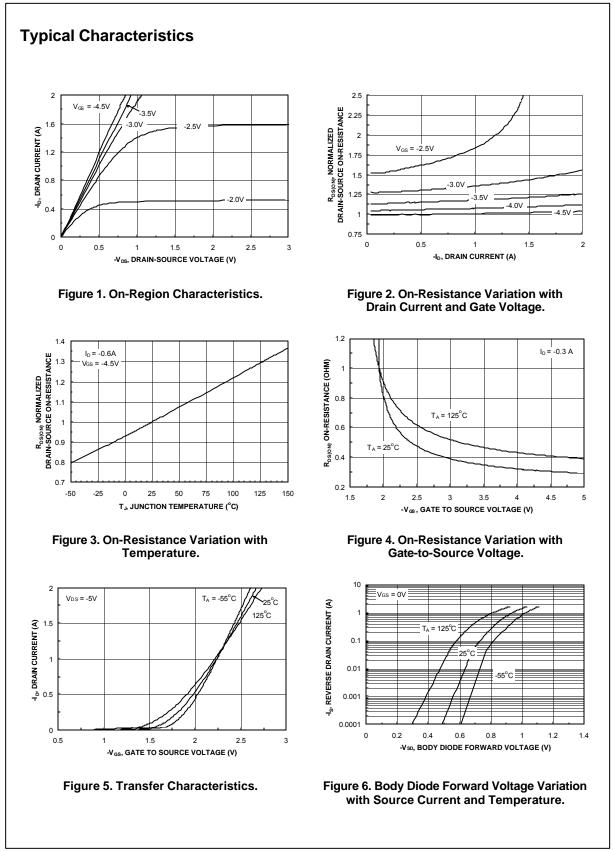
The pinouts are symmetrical; pin 1 and pin 4 are interchangeable.

Symbol	Parameter			Ratings	Units	
V _{DSS}	Drain-Source Voltage			-20	V	
V _{GSS}	Gate-Source Voltage			±12	V	
Ь	Drain Curre	nt – Continuous	(Note 1)	-0.6	A	
	– Pulsed			-2.0		
PD	Power Diss	ipation for Single Opera	ation (Note 1)	0.3	W	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			–55 to +150		
Therma	al Charact	teristics				
R _{0JA}	Thermal Re	teristics sistance, Junction-to-A g and Ordering		415	°C/W	
R _{eja} Packag	Thermal Re	sistance, Junction-to-A		415 Tape width	°C/₩	

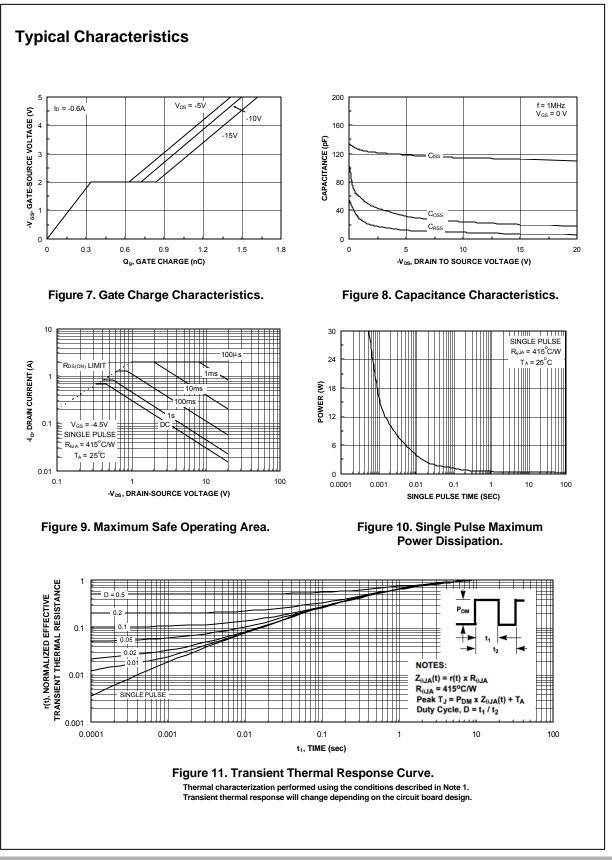
Symbol	Parameter	Test Conditions	Min	Тур	Мах	Units
Off Cha	racteristics					•
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = -250 \mu A$	-20			V
ΔBV_{DSS} ΔT_J	Breakdown Voltage Temperature Coefficient	I_D = –250 µA, Referenced to 25°C		-14		mV/°C
DSS	Zero Gate Voltage Drain Current	$V_{DS} = -16 V, V_{GS} = 0 V$			–1	μA
GSSF	Gate-Body Leakage, Forward	$V_{GS} = -12 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
GSSR	Gate–Body Leakage, Reverse	$V_{GS} = 12 V, V_{DS} = 0 V$			100	nA
On Cha	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-0.6	-1.2	-1.5	V
<u>ΔVgs(th)</u> ΔTj	Gate Threshold Voltage Temperature Coefficient	I_D = –250 µA, Referenced to 25°C		3		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{\rm GS} = -4.5 \ V, \ b = -0.6 \ A \\ V_{\rm GS} = -2.5 \ V, \ b = -0.5 \ A \\ V_{\rm GS} = -4.5 \ V, \ b = -0.6 \ A, \ T_{\rm J} = 125^{\circ} C \\ \end{array} \\ \begin{array}{l} V_{\rm GS} = -4.5 \ V, \ b_{\rm D} = -5 \ V \end{array} $		300 470 400	420 630 700	mΩ
D(on)	On–State Drain Current	V_{GS} = -4.5 V, V_{DS} = -5 V	-2			A
9 _{FS}	Forward Transconductance	$V_{DS} = -5 V$, $I_{D} = -0.6 A$		1.8		S
Dynami	c Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = -10 V$, $V_{GS} = 0 V$,		114		pF
Coss	Output Capacitance	f = 1.0 MHz		24		pF
C _{rss}	Reverse Transfer Capacitance			9		pF
Switchi	ng Characteristics (Note 2)					
d(on)	Turn–On Delay Time	$V_{DD} = -10 \text{ V}, I_D = 1 \text{ A},$		5.5	11	ns
tr	Turn–On Rise Time	V_{GS} = -4.5 V, R_{GEN} = 6 Ω		14	25	ns
t _{d(off)}	Turn–Off Delay Time			6	12	ns
f	Turn–Off Fall Time			1.7	3.4	ns
Qg	Total Gate Charge	$V_{DS} = -10 V$, $I_D = -0.6 A$,		1.4	2.0	nC
Q _{gs}	Gate–Source Charge	$V_{GS} = -4.5 V$		0.3		nC
Q _{gd}	Gate–Drain Charge			0.4		nC
Drain–S	ource Diode Characteristic	s and Maximum Ratings				
s	Maximum Continuous Drain–Source				-0.25	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = -0.25 A(Note 2)$		-0.77	-1.2	V

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2. Pulse Test: Pulse Width < 300 μ s, Duty Cycle < 2.0%



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